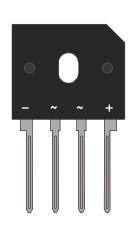
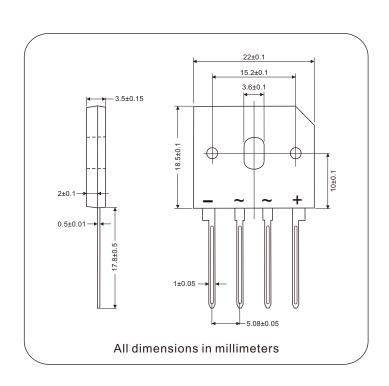




Nell High Power Products

Glass Passivated Single-Phase Bridge Rectifier, 8A GBU8D Thru GBU8M





FEATURES

- UL recognition file number E320098
- **AV**
- Typical IR less than 2.0 μA
- High surge current capability
- Low thermal resistance
- Compliant to RoHS
- Isolation voltage up to 2500V

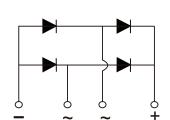
TYPICAL APPLICATIONS

General purpose use in AC/DC bridge full wave rectification for big power supply, field supply for DC motor, industrial automation applications.

ADVANTAGE

- International standard package
 Epoxy meets UL 94 V-0 flammability rating
- Small volume, light weight
- Small thermal resistance
- High heat-conduction rate
- Low temperature rise
- High temperature soldering guaranteed : 260°C/10 second, 2.3kg tension force
- Weight: 4.0g (0.14 ozs)





PRIMARY CHARACTERRISTICS						
I _{F(AV)}	8A					
V_{RRM}	400V to 1000V					
I _{FSM}	200A					
I _R	5 μΑ					
V _F	1.10V					
T _{J max} .	150°C					



Nell High Power Products

MAJOR RATINGS AND CHARACTERISTICS (T _A = 25°C unless otherwise noted)								
PARAMETER	SYMBOL	GBU8						
		D	G	J	K	М	UNIT	
Maximum repetitive peak reverse voltage	V_{RRM}	200	400	600	800	1000	V	
Peak reverse non-repetitive voltage	V _{RSM}	300	500	700	900	1100	V	
Maximum DC blocking voltage	V _{DC}	200	400	600	800	1000	V	
Maximum average forward rectified output current, T _c = 85°C	I _{F(AV)}	8					Α	
Peak forward surge current single sine-wave superimposed on rated load	I _{FSM}	200				Α		
Rating (non-repetitive, for t greater than 1 ms and less than 8.3 ms) for fusing	l ² t	166				A ² s		
RMS isolation voltage from case to leads	V _{ISO}	2500				V		
Operating junction storage temperature range	TJ	-40 to 150				°C		
Storage temperature range	T _{STG}	-40 to 150			°C			

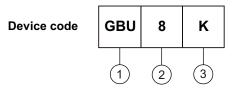
ELECTRICAL CHARACTERISTICS (T _A = 25°C unless otherwise noted)									
PARAMETER	TEST CONDITIONS	SYMBOL	GBU8						
			D	G	J	K	M	UNIT	
Maximum instantaneous forward drop per diode	I _F = 4A	V _F	1.10				٧		
Maximum reverse DC current at rated DC blocking	O A == 0		5					μA	
voltage per diod	T _A = 150°C	I _R	500					μΑ	

THERMAL AND MECHANICAL (T _A = 25°C unless otherwise noted)									
PARAMETER TEST CONDITIONS	TEST CONDITIONS	SYMBOL	GBU8						
	TEST CONDITIONS		D	G	J	K	М	UNIT	
Typical thermal resistance junction to case	Single-side heat dissipation, sine half wave	$R_{\theta JC}^{(1)}$			4.0			°C/W	
Mounting torque to heatsink M3 ± 10 %	A mounting compound is recommended and the torque should be rechecked after a period of 3 hours to allow for the spread of the compound.		0.8			N⋅m			
Approximate weight					4.0			g	

Notes

(1) With heatsink, single side heat dissipation, half sine wave.

Ordering Information Tabel



1 - Product type : "GBU" Package,1Ø Bridge

I_{F(AV)} rating: "8" for 8A
 Voltage code: D = 200V

G = 400V J = 600V K = 800V M = 1000V



Nell High Power Products

Fig.1 Derating curve for output rectified current

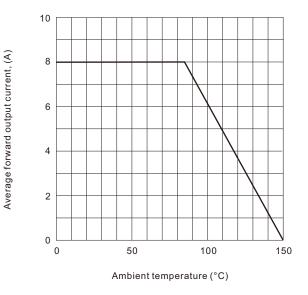


Fig.2 Maximum non-repetitive peak forward surge current per bridge element

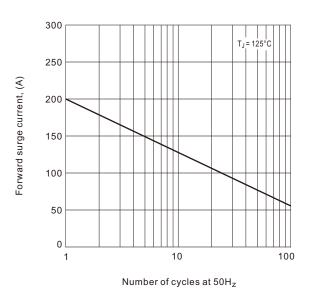


Fig.3 Typical reverse characteristics per bridge element

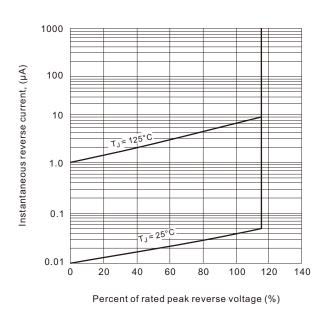
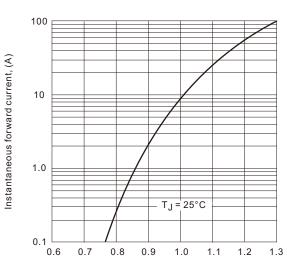


Fig.4 Typical forward characteristics per bridge element



Forward voltage (V)